



#### 60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
	$8m\Omega$ @ $V_{GS} = 10V$	70A
60V	12mΩ @ V <sub>GS</sub> = 4.5V	50A

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DCDC Converters

#### **Features**

- Rated to 175°C ideal for high ambient temperature environments
- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- Low On-Resistance
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

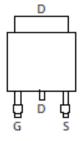
### **Mechanical Data**

- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
   Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.33 grams (Approximate)

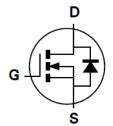




Top View



Pin Out Top View



**Equivalent Circuit** 

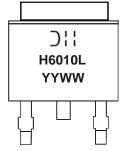
### Ordering Information (Note 5)

Part Number	Case	Packaging
DMTH6010LK3Q-13	TO252	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. For more information, please refer to http://www.diodes.com/product\_compliance\_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



] | | = Manufacturer's Marking H6010L = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 15 = 2015) WW = Week Code (01 to 53)



# **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	$V_{DSS}$	60	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	14.8 11.9	А
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 7)	$T_C = +25^{\circ}C$ $T_C = +100^{\circ}C$	$I_D$	70 50	Α
Maximum Continuous Body Diode Forward Current (Note 7)	Is	60	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	130	Α	
Avalanche Current, L = 0.1mH	I <sub>AS</sub>	20	Α	
Avalanche Energy, L = 0.1mH	E <sub>AS</sub>	20	mJ	

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P <sub>D</sub>	31	W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	47	°C/W
Total Power Dissipation (Note 7)	P <sub>D</sub>	60	W
Thermal Resistance, Junction to Case (Note 7)	$R_{\theta JC}$	2.5	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

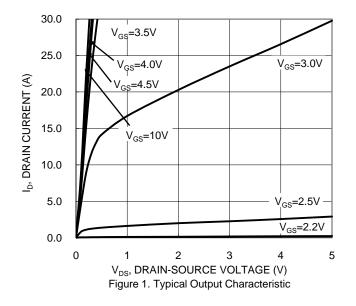
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

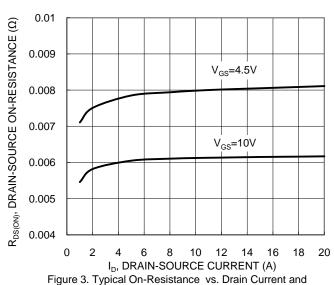
<u> </u>							
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	-	-	V	$V_{GS} = 0V$ , $I_D = 1mA$	
		-	ı	1	μA	$V_{DS} = 48V$ , $V_{GS} = 0V$	
Zero Gate Voltage Drain Current (Note 9)	I <sub>DSS</sub>	1	-	100	μΑ	$V_{DS} = 48V, V_{GS} = 0V,$ $T_{J} = 125^{\circ}C$	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	-	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		-	6.3	8	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 20A	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	-	8.3	12		$V_{GS} = 4.5V, I_D = 20A$	
Diode Forward Voltage	V <sub>SD</sub>	-	0.9	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 20A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	-	2090	-		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	-	746	-	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	-	38.5	-		1 = 11011 12	
Gate Resistance	$R_g$	0.1	0.59	1.8	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_g$	-	19.3	-			
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_g$	-	41.3	-	nC	), 00\/ I 00A	
Gate-Source Charge	$Q_{gs}$	-	6	-	110	$V_{DS} = 30V, I_{D} = 20A$	
Gate-Drain Charge	$Q_{gd}$	-	8.8	-			
Turn-On Delay Time	t <sub>D(ON)</sub>	-	5.7	-		V <sub>DD</sub> = 30V, V <sub>GS</sub> = 10V,	
Turn-On Rise Time	t <sub>R</sub>		4.3	-	ns		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	-	23.4	-	115	$I_D=20A,\ R_g=3\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	-	9.7	-			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	-	35.4	-	ns		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	-	38.2	-	nC	$\frac{1}{1}$ IF = 20A, di/dt = 100A/µs	

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.7. Thermal resistance from junction to soldering point (on the exposed drain pad).8. Short duration pulse test used to minimize self-heating effect. Notes:

9. Guaranteed by design. Not subject to product testing.







Gate Voltage

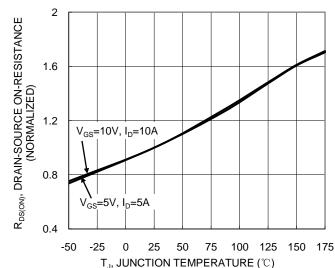


Figure 5. On-Resistance Variation with Temperature

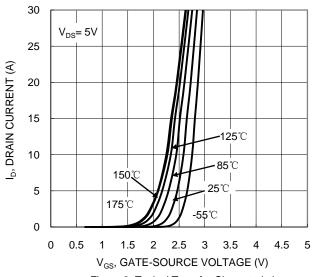


Figure 2. Typical Transfer Characteristic

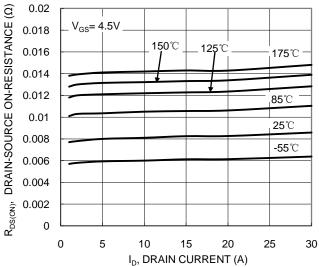


Figure 4. Typical On-Resistance vs. Drain Current and Temperature

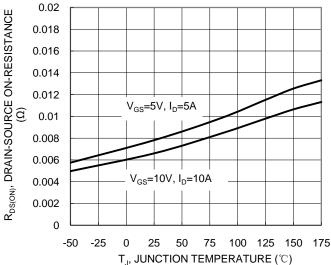
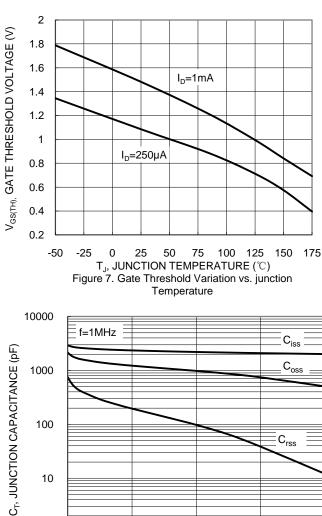
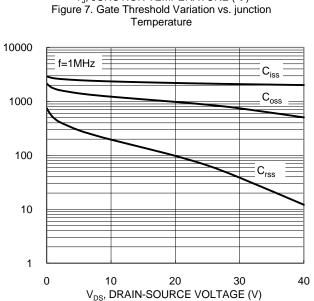
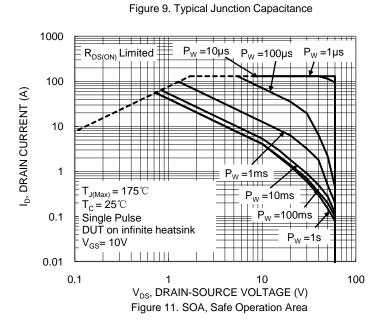


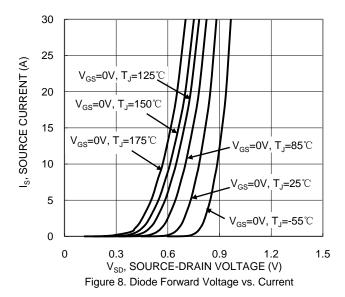
Figure 6. On-Resistance Variation with Temperature

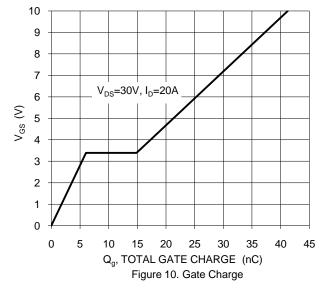














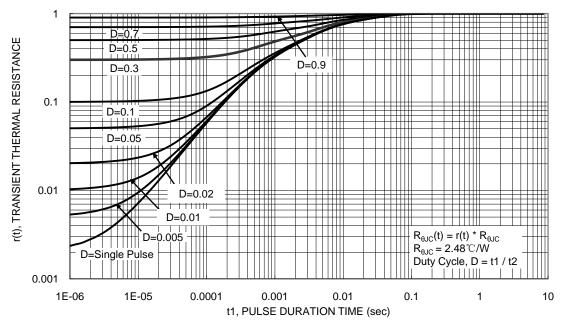
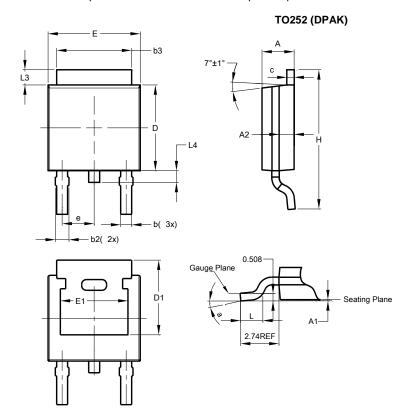


Figure 12 . Transient Thermal Resistance



### **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

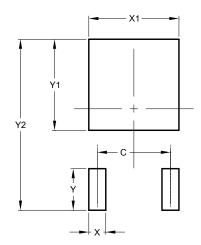


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
<b>A</b> 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
q	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
H	9.40	10.41	9.91		
٦	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### TO252 (DPAK)



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Υ	2.600		
Y1	5.700		
Y2	10.700		



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